

SiC Schottky Barrier Diode

V_R	650V
I _F	12A
Q_{C}	28nC

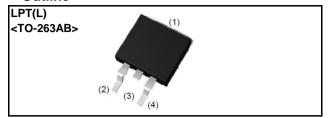
Features

- 1) Low forward voltage
- 2) Negligible recovery time/current
- 3) Temperature independent switching behavior
- 4) High surge current capability
- 5) Low leakage current

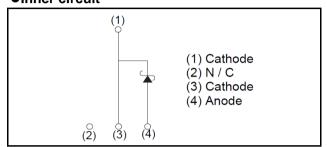
Applications

- Switch Mode Power Supply
- Uninterruptible Power Supply
- ·Solar Inverter
- Motor Drive
- · Air Conditioner
- •EV Charger

Outline



●Inner circuit



Packaging specifications

Tackaging specifications		
	Packaging	Embossed tape
	Reel size (mm)	330
Tuno	Tape width (mm)	24
Туре	Basic ordering unit (pcs)	1.000
	Packing code	TLL
	Marking	SCS312AJ

● Absolute maximum ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (re	petitive peak)	V_{RM}	650	V
Reverse voltage (De	C)	V _R	650	V
Continuous forward	current (T _c = 135°C)	I _F	12	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		96	А
repetitive forward PW=10ms sinusoidal, T _j =150°C		I _{FSM}	81	А
current	PW=10μs square, T _j =25°C		350	А
Repetitive peak forward current		I _{FRM}	55 ^{*1}	А
1≦PW≦10ms, T _j =25°C		ر _۱ ۰۶ ۱۰	46	A ² s
i ² t value 1≦PW≦10ms, T _j =150°C		$\int i^2 dt$	32	A ² s
Total power disspation		P _D	88 *2	W
Junction temperature		Tj	175	°C
Range of storage temperature		T _{stg}	−55 to +175	°C

^{*1} T_c =100°C, T_j =150°C, Duty cycle=10% *2 T_c =25°C

●Electrical characteristics (T_i = 25°C)

Parameter S	Sumbol	Conditions	Values			Unit
	Symbol	Conditions	Min.	Тур.	Max.	Unii
DC blocking voltage	V_{DC}	I _R =60μA	650	-	-	V
	V _F	I _F =12A,T _j =25°C	-	1.35	1.50	V
Forward voltage		I _F =12A,T _j =150°C	-	1.44	1.71	V
		I _F =12A,T _j =175°C	-	1.50	-	V
	I _R	V _R =650V,T _j =25°C	=	0.036	60	μА
Reverse current		V _R =650V,T _j =150°C	-	2.4	240	μΑ
		V _R =650V,T _j =175°C	-	7.2	-	μА
Total capacitance	С	V _R =1V,f=1MHz	=	600	-	pF
		V _R =650V,f=1MHz	-	55	-	pF
Total capacitive charge	Q _C	V _R =400V,di/dt=350A/μs	-	28	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	18	-	ns
Non-repetetive Avaranche Energy	E _{ava}	L=1mH	-	150	-	mJ

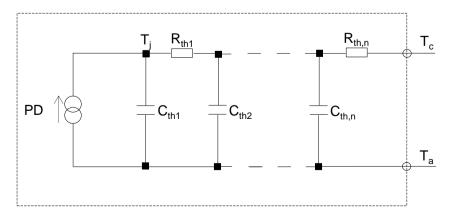
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	R _{th(j-c)}	-	-	1.2	1.7	°C/W

●Typical Transient Thermal Characteristics

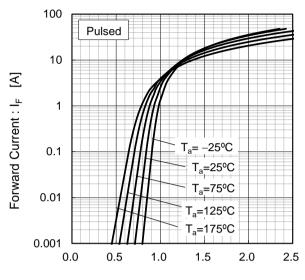
Symbol	Value	Unit
R _{th1}	1.58E-01	
R _{th2}	1.06E+00	K/W
R _{th3}	1.01E-03	

Symbol	Value	Unit
C _{th1}	2.30E-04	
C _{th2}	3.55E-03	Ws/K
C _{th3}	3.99E+00	



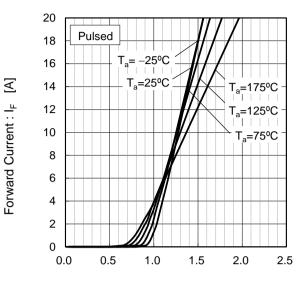
•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics



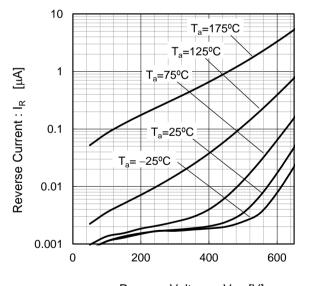
Forward Voltage : V_F [V]

Fig.2 V_F - I_F Characteristics



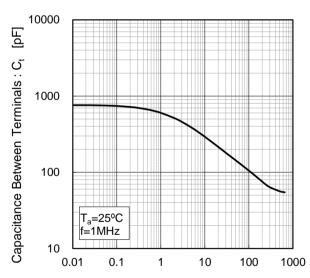
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

Fig.4 V_R-C_t Characteristics



Reverse Voltage : V_R [V]

Electrical characteristic curves

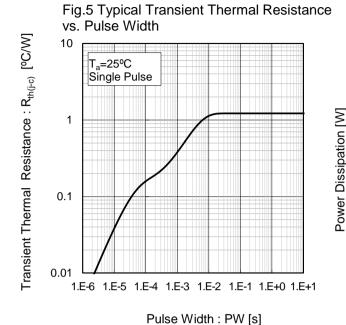
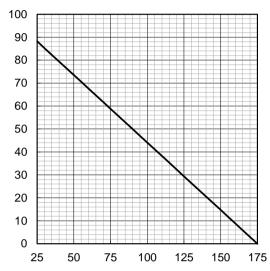
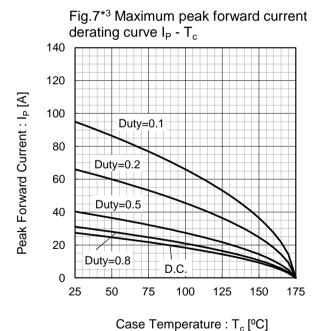


Fig.6 Power Dissipation



Case Temperature : T_c [°C]



Peak Forward Current : I_P [A] 100 80 60

derating curve I_P - T_c (Not guaranteed) 140 Duty=0.1 120 Duty=0.2 Duty=0.5 40 20 Duty=0.8 D.C. 0 25 50 75 100 125 150 175

Fig.8*4 Typical peak forward current

 $^{\star}3$ Based on max Vf, max $R_{\text{th(j-c)}}$ Valid for switching of above 10kHz, excluding D.C. curve.

Case Temperature : T_c [°C] *4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)

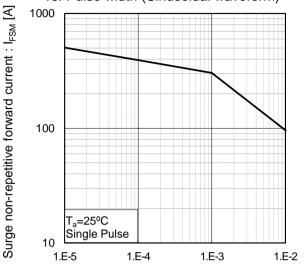
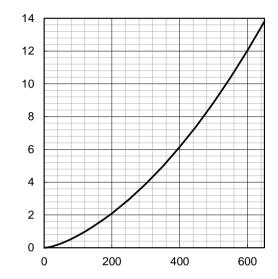


Fig.10 Typical capacitance store energy



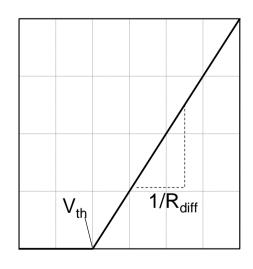
Capacitance stored energy : $E_C[\mu J]$

Reverse Voltage : V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve

Pulse Width: PW [s]



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} & V_{th} \left(\ T_{j} \ \right) = a_{0} + a_{1} \, T_{j} \\ & R_{diff} \left(\ T_{j} \ \right) = b_{0} + b_{1} \, T_{j} + b_{2} \, T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
a ₀	9.66E-01	V
a ₁	-1.10E-03	V/°C
b ₀	2.93E-02	Ω
b ₁	6.22E-05	Ω/°C
b ₂	6.40E-07	$\Omega/^{\circ}C^{2}$

 T_i in °C; -55 °C < T_i < 175°C; I_F < 24 A

Forward Current: IF

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SCS312AJ - Web Page

Part Number	SCS312AJ
Package	TO-263AB (LPTL)
Unit Quantity	1000
Minimum Package Quantity	1000
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes